

TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS151C

September 1997 - Revised October 2003

Features

- Common Select Inputs
- Separate Enable Inputs
- Buffered inputs and Outputs
- Fanout (Over Temperature Range)
- Standard Outputs..... 10 LSTTL Loads
- Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $\textbf{I}_{I} \leq 1 \mu \textbf{A}$ at $\textbf{V}_{\textbf{OL}},\,\textbf{V}_{\textbf{OH}}$

^{из}СD54HC153, CD74HC153, CD54HCT153, CD74HCT153

High-Speed CMOS Logic Dual 4- to 1-Line Selector/Multiplexer

Description

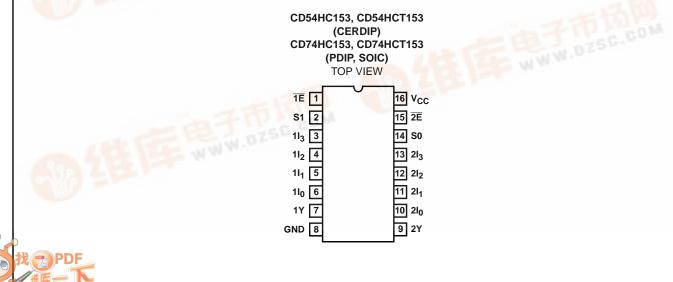
The 'HC153 and 'HCT153 are dual 4- to 1-line selector/multiplexers that select one of four sources for each section by the common select inputs, S0 and S1. When the enable inputs $(1\overline{E}, 2\overline{E})$ are HIGH, the outputs are in the LOW state.

Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD54HC153F3A	-55 to 125	16 Ld CERDIP
CD54HCT153F3A	-55 to 125	16 Ld CERDIP
CD74HC153E	-55 to 125	16 Ld PDIP
CD74HC153M	-55 to 125	16 Ld SOIC
CD74HC153MT	-55 to 125	16 Ld SOIC
CD74HC153M96	-55 to 125	16 Ld SOIC
CD74HCT153E	-55 to 125	16 Ld PDIP
CD74HCT153M	-55 to 125	16 Ld SOIC
CD74HCT153MT	-55 to 125	16 Ld SOIC
CD74HCT153M96	-55 to 125	16 Ld SOIC

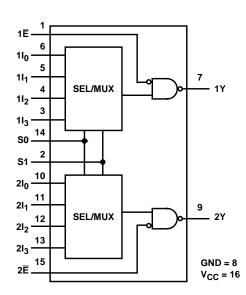
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout



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CALITION: These devices are consitive to electrostatic discharge. Llears should fellow proper IC Handling Presedures



Functional Diagram

TRUTH TABLE

SELECT	INPUTS		DATA I	ENABLE	OUTPUT		
S1	S0	10	I ₁	l ₂	I ₃	Ē	Y
х	х	х	х	х	х	Н	L
L	L	L	х	х	х	L	L
L	L	н	х	х	х	L	н
L	н	х	L	х	х	L	L
L	н	х	Н	х	х	L	н
н	L	х	х	L	х	L	L
н	L	х	х	н	х	L	н
Н	н	х	х	х	L	L	L
Н	Н	Х	Х	Х	Н	L	Н

H = High Voltage Level, L = Low Voltage Level, X = Don't Care NOTE: Select inputs S1 and S0 are common to both sections.

Absolute Maximum Ratings

DC Supply Voltage, V_CC \ldots -0.5V to 7V
DC Input Diode Current, I _{IK}
For V _I < -0.5V or V _I > V _{CC} + 0.5V
DC Output Diode Current, IOK
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC or} I _{GND} ±50mA

Operating Conditions

Temperature Range (T _A)55°C to 125° C Supply Voltage Range, V _{CC}
HC Types
HCT Types4.5V to 5.5V
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical, Note 1)	θ _{JA} (^o C/W)
E (PDIP) Package	67
M (SOIC) Package	
Maximum Junction Temperature	
Maximum Storage Temperature Range6	5 ⁰ C to 150 ⁰ C
Maximum Lead Temperature (Soldering 10s) (SOIC - Lead Tips Only)	300 ⁰ C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TEST CONDITIONS V _{CC} 2		25 ⁰ C		25 [°] C -40 [°] C TO 85 [°] C			O 125 ⁰ C			
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(Ŭ)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	VIL	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output Voltage TTL Loads	1		-	-	-	-	-	-	-	-	-	V
			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	L VIH or VIL	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
CINCO LOADS			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μA

		TEST CONDITIONS		v _{cc}		25 ⁰ C		-40 ^о С т	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES	-							-	-	-		
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} and GND	0	5.5	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	lcc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA

NOTE:

2. For dual-supply systems theoretical worst case (VI = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS				
Data	0.45				
Enable	0.6				
Select	1.35				

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g. 360µA max at 25°C.

Switching Specifications Input t_r , $t_f = 6ns$

		TEST			25 ⁰ C		-40 ⁰ 85	с то ⁰С		С ТО 5°С	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES		-									
Propagation Delay (Figure 1)	t _{PLH,}	$C_L = 50 pF$	2	-	-	160	-	200	-	240	ns
S to Y	t _{PHL}		4.5	-	-	32	-	40	-	48	ns
		C _L =15pF	5	-	13	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	27	-	34	-	41	ns

		TEST	v _{cc}	25 ⁰ C			-40°С ТО 85 [°] С		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
I to Y	^t PLH,	C _L = 50pF	2	-	-	145	-	180	-	220	ns
	^t PHL		4.5	-	-	29	-	36	-	44	ns
		C _L =15pF	5	-	12	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	25	-	31	-	38	ns
E to Y	t _{PLH,}	C _L = 50pF	2	-		120	-	150	-	180	ns
	^t PHL		4.5	-		24	-	30	-	36	ns
		C _L =15pF	5	-	9	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	20	-	26	-	31	ns
Output Transition Time (Figure 1)	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	CIN	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	45	-	-	-	-	-	pF
HCT TYPES	-			-							
Propagation Delay (Figure 2) S to Y	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	34	-	43	-	51	ns
		C _L =15pF	5	-	14	-	-		-	-	ns
I to Y	t _{PLH} ,	C _L = 50pF	4.5	-	-	24	-	30	-	36	ns
	^t PHL	C _L =15pF	5	-	9	-	-	-	-	-	ns
I to Y	t _{PLH} ,	C _L = 50pF	4.5	-		34	-	43	-	51	ns
	^t PHL	C _L =15pF	5	-	14	-	-	-	-	-	ns
E to Y	t _{PLH} ,	C _L = 50pF	4.5	-	-	27	-	34	-	41	ns
	^t PHL	C _L =15pF	5	-	11	-	-		-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C _{IN}	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	45	-	-	-	-	-	pF

NOTES:

3. C_{PD} is used to determine the dynamic power consumption, per multiplexer. 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuit and Waveform

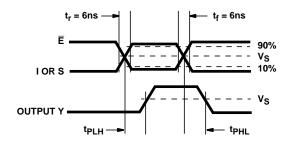


FIGURE 1. PROPAGATION DELAY TIMES



PACKAGE OPTION ADDENDUM

28-Feb-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
5962-9050501MEA	ACTIVE	CDIP	J	16	1	None	Call TI	Level-NC-NC-NC
CD54HC153F3A	ACTIVE	CDIP	J	16	1	None	Call TI	Level-NC-NC-NC
CD54HCT153F3A	ACTIVE	CDIP	J	16	1	None	Call TI	Level-NC-NC-NC
CD74HC153E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC153M	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HC153M96	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HC153MT	ACTIVE	SOIC	D	16	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT153E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HCT153M	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT153M96	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT153MT	ACTIVE	SOIC	D	16	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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J (R-GDIP-T**) 14 LEADS SHOWN

PINS ** 14 16 20 18 DIM 0.300 0.300 0.300 0.300 В Α (7,62) (7,62) (7,62) (7,62) BSC BSC BSC BSC 14 8 0.785 .840 0.960 1.060 B MAX (19, 94)(21, 34)(24, 38)(26, 92)B MIN С 0.300 0.300 0.310 0.300 C MAX (7, 62)(7, 62)(7, 87)(7, 62)7 0.245 0.245 0.220 0.245 0.065 (1,65) C MIN (6, 22)(6,22) (5, 59)(6,22) 0.045 (1,14) 0.060 (1,52) ← 0.005 (0,13) MIN Α 0.015 (0,38) 0.200 (5,08) MAX Seating Plane 0.130 (3,30) MIN 0.026 (0,66) 0.014 (0,36) 0'-15' 0.100 (2,54) 0.014 (0,36) 0.008 (0,20) 4040083/F 03/03

CERAMIC DUAL IN-LINE PACKAGE

NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

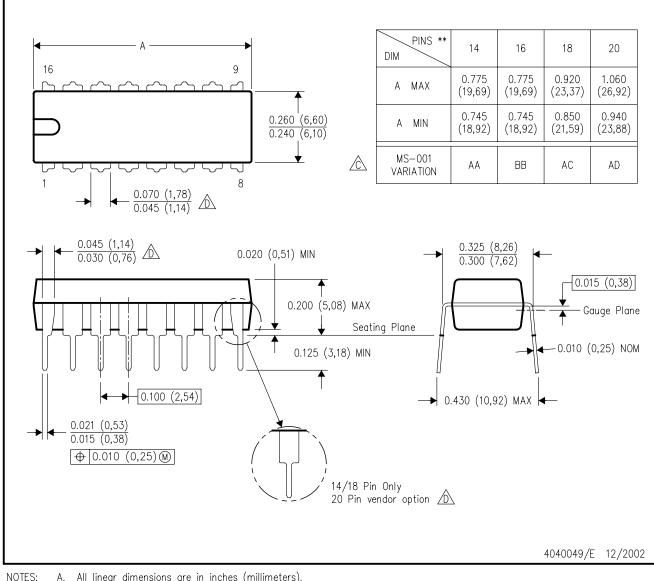
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.

E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

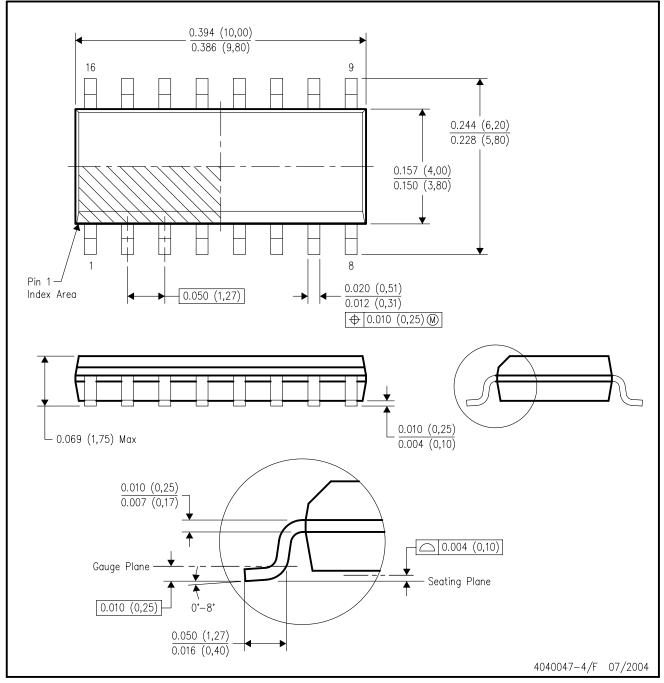
🖄 Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).

The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012 variation AC.



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